NSN 5961-01-361-2299

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Field effect

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-205af

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

400.0 drain to source voltage and 400.0 drain to gate voltage and 400.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source

Test Data Document:

81349-mil-s-19500h specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Specification Data:

81349-mil-s-19500/556b government specification

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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